

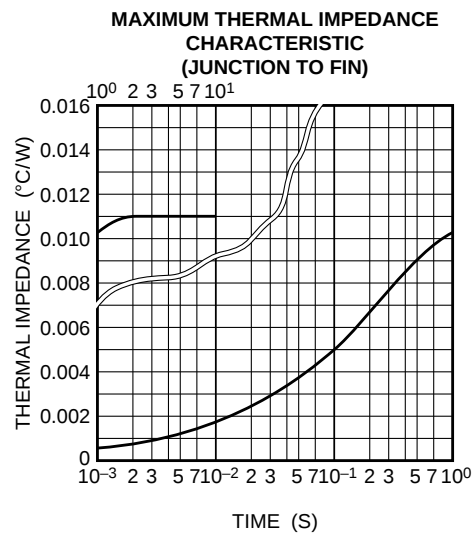
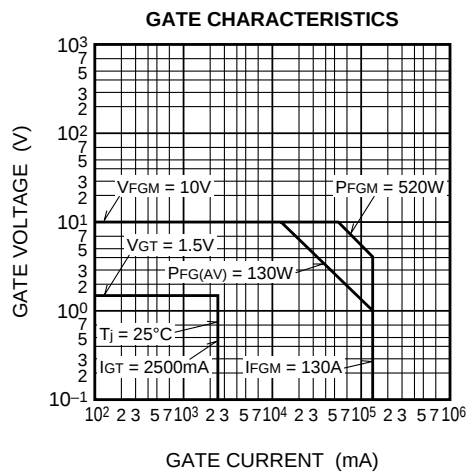
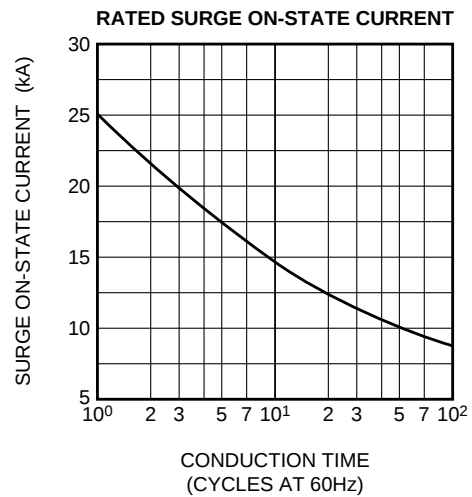
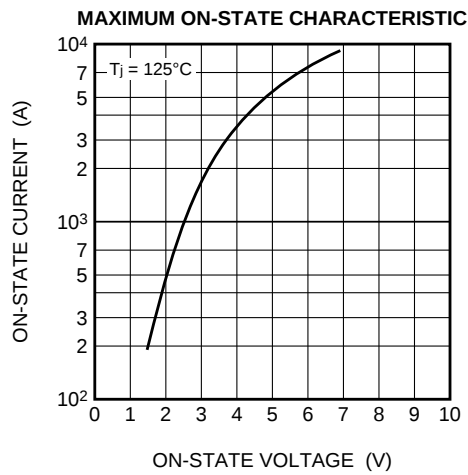
FG4000GX-90DA

HIGH POWER INVERTER USE
PRESS PACK TYPE

ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test conditions	Limits			Unit
			Min	Typ	Max	
V _{TM}	On-state voltage	T _j = 125°C, I _{TM} = 4000A, Instantaneous measurment	—	—	4.3	V
I _{RRM}	Repetitive peak reverse current	T _j = 125°C, V _{RRM} Applied	—	—	10	mA
I _{DRM}	Repetitive peak off-state current	T _j = 125°C, V _{DRM} Applied, V _{GK} = -2V	—	—	150	mA
I _{RG}	Reverse gate current	T _j = 125°C, V _{RG} = 17V	—	—	10	mA
dv/dt	Critical rate of rise of off-state voltage	T _j = 125°C, V _D = 2250V, V _{GK} = -2V	1000	—	—	V/μs
t _{gt}	Turn-on time	T _j = 125°C, I _{TM} = 4000A, I _{GM} = 25A, V _D = 3400V	—	—	8	μs
t _{gq}	Turn-off time	T _j = 125°C, I _{TM} = 4000A, V _{DM} = 4500V, diGQ/dt = -50A/μs V _{RG} = 17V, C _S = 4.0μF, L _S = 0.2μH	—	—	35	μs
I _{GQM}	Peak gate turn-off current		—	900	—	A
V _{GT}	Gate trigger voltage	DC METHOD : V _D = 24V, R _L = 0.1Ω, T _j = 25°C	—	—	1.5	V
I _{GT}	Gate trigger current		—	—	2500	mA
R _{th(j-f)}	Thermal resistance	Junction to fin	—	—	0.011	°C/W

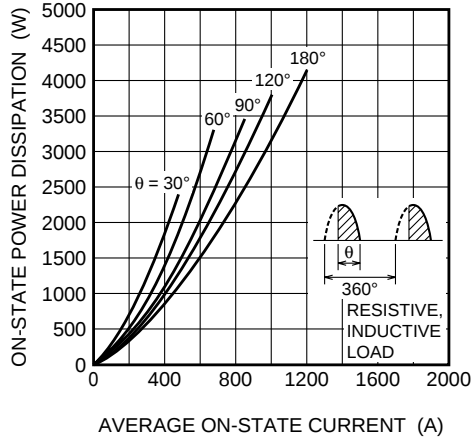
PERFORMANCE CURVES



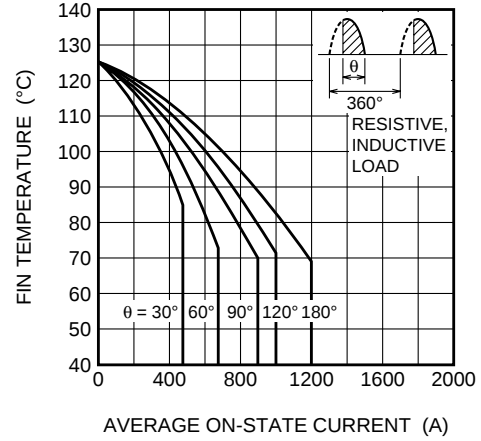
FG4000GX-90DA

HIGH POWER INVERTER USE
PRESS PACK TYPE

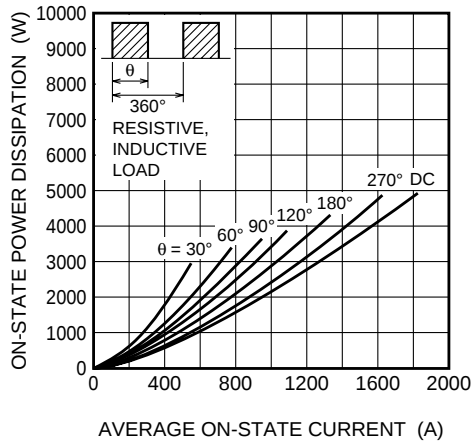
**MAXIMUM ON-STATE POWER DISSIPATION
CHARACTERISTICS
(SINGLE-PHASE HALF WAVE)**



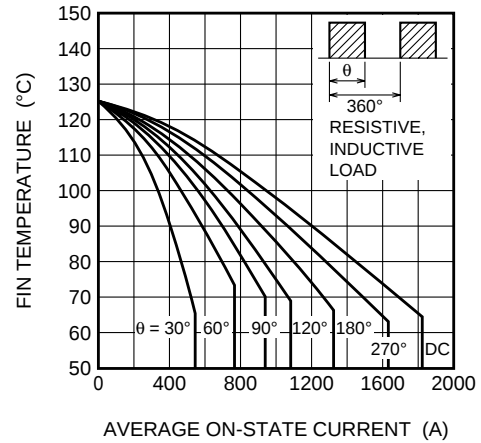
**ALLOWABLE FIN TEMPERATURE VS.
AVERAGE ON-STATE CURRENT
(SINGLE-PHASE HALF WAVE)**



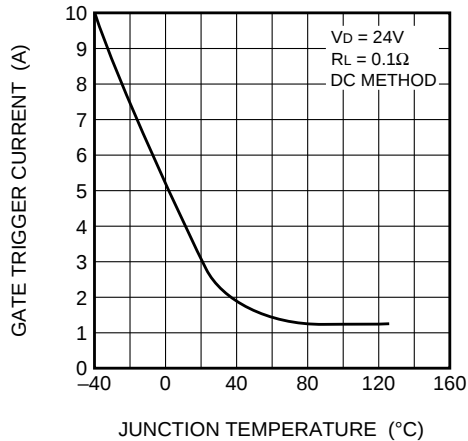
**MAXIMUM ON-STATE POWER DISSIPATION
CHARACTERISTICS
(RECTANGULAR WAVE)**



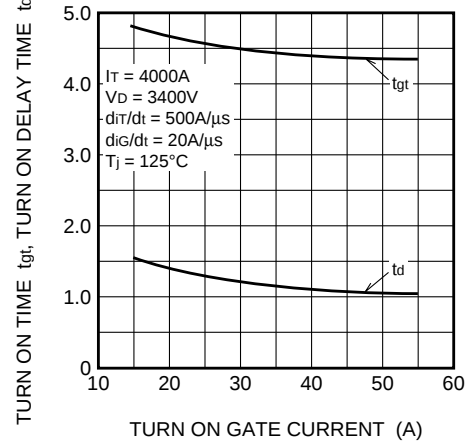
**ALLOWABLE FIN TEMPERATURE VS.
AVERAGE ON-STATE CURRENT
(RECTANGULAR WAVE)**



**GATE TRIGGER CURRENT VS.
JUNCTION TEMPERATURE
(MAXIMUM)**



**TURN ON TIME, TURN ON DELAY TIME
VS. TURN ON GATE CURRENT
(TYPICAL)**



FG4000GX-90DA

HIGH POWER INVERTER USE
PRESS PACK TYPE

